

TOSHIBA BIPOLAR DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

**TD62384AP, TD62384F, TD62384AF
TD62385AP, TD62385F, TD62385AF**

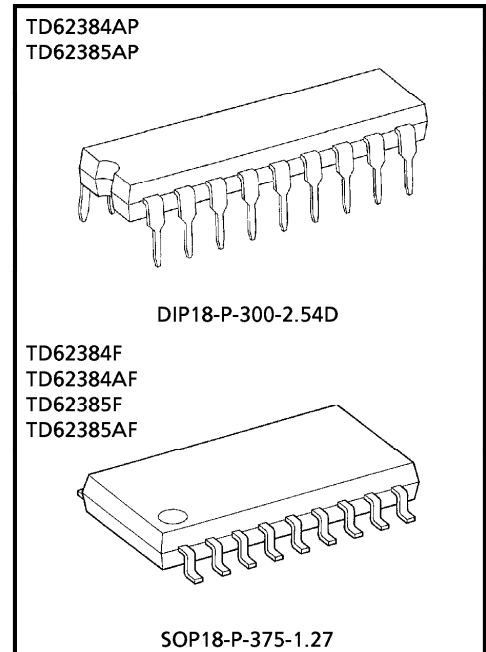
8CH LOW INPUT ACTIVE DARLINGTON SINK DRIVER

The TD62384AP/F/AF and TD62385AP/F/AF are non-inverting transistor arrays, which are comprised of eight NPN darlington output stages and PNP input stages. These devices are Low Level input active drivers and are suitable for operations with TTL, 5V CMOS and 5V Microprocessor which have sink current output drivers. Applications include relay, hammer, lamp and LED driver.

FEATURES

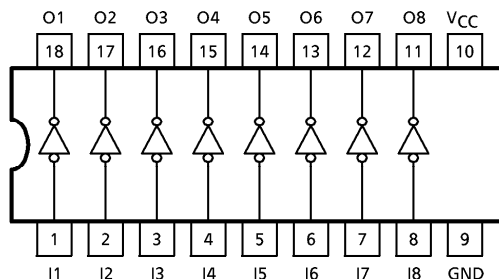
- Output current (single output) 500mA (Max.)
- High sustaining voltage 35V (TD62384F, 385F) 50V (TD62384AP/AF, 385AP/AF) (Min.)
- Low level active input
- Standard supply voltage
- Inputs compatible with TTL and 5V CMOS
- Package type-AP : DIP-18pin
- Package type-F, AF : SOP-18pin

TYPE	V _{IN} (ON)
TD62384AP/F/AF	-20V~V _{CC} -2.8V
TD62385AP/F/AF	0V~V _{CC} -3.7V



Weight
 DIP18-P-300-2.54D : 1.47g (Typ.)
 SOP18-P-375-1.27 : 0.41g (Typ.)

PIN CONNECTION (TOP VIEW)

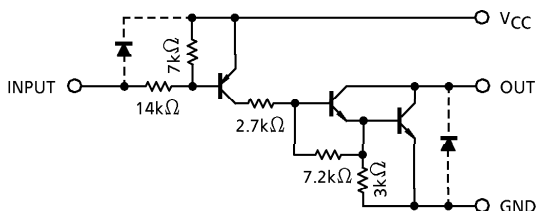


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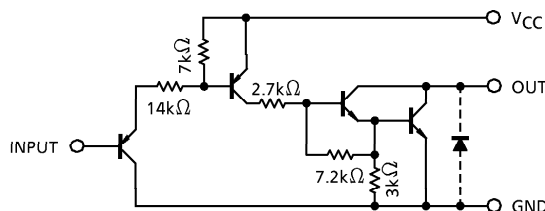
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SCHEMATICS (EACH DRIVER)

TD62384AP / F / AF



TD62385AP / F / AF



(*) The input and output parasitic diodes cannot be used as clamp diodes.

MAXIMUM RATING (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
Supply Voltage		V _{CC}	- 0.5~7.0	V
Output Sustaining Voltage	AP / AF	V _{CE (SUS)}	- 0.5~50	V
	F		- 0.5~35	
Output Current		I _{OUT}	500	mA / ch
Input Voltage	V _{IN} (Note 1)		- 22~V _{CC} + 0.5	V
	V _{IN} (Note 2)		- 0.5~7	
Input Current		I _{IN}	- 10	mA
Power Dissipation	AP	P _D (Note 3)	1.47	W
	F / AF		0.96	
Operating Temperature		T _{opr}	- 40~85	°C
Storage Temperature		T _{stg}	- 55~150	°C

(Note 1) TD62384AP / AF / F

(Note 2) TD62385AP / AF / F

(Note 3) Delated above 25°C in the proportion of 11.7mW/°C (AP-Type), 7.7mW/°C (F, AF-Type).

RECOMMENDED OPERATING CONDITIONS (Ta = - 40~85°C)

CHARACTERISTIC		SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
Supply Voltage		V _{CC}	—	4.5	5.0	5.5	V
Output Sustaining Voltage	AP / AF	V _{CE (SUS)}	—	0	—	50	V
	F		—	0	—	35	
Output Current	AP	I _{OUT}	T _{pw} = 25ms, Duty = 50%, 8 Circuits	0	—	115	mA / ch
	F / AF		Ta = 85°C, T _j = 120°C	0	—	78	
			T _{pw} = 25ms, Duty = 10%, 1 Circuit	0	—	400	
Input Voltage	TD62384	V _{IN}	—	- 20	—	V _{CC}	V
	TD62385		—	0	—	5.5	
Power Dissipation	AP	P _D	—	—	—	0.52	W
	F / AF		—	—	—	0.35	

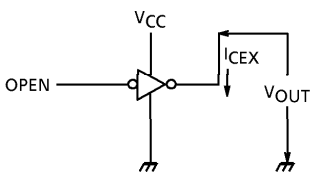
ELECTRICAL CHARACTERISTIC (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CIRCUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT	
Output Leakage Current	AP / AF	I _{CEX}	1	V _{CC} = 5.5V, I _{IN} = 0, Ta = 85°C	V _{OUT} = 50V	—	—	100	μA
	F				V _{OUT} = 35V				
Output Saturation Voltage		V _{CE (sat)}	2	V _{CC} = 4.5V, I _{OUT} = 350mA V _{IN} = V _{IN (ON)} MAX.	—	1.4	2.0	V	
Input Current	(Output On)	I _{IN (ON)}	3	V _{CC} = 5.5V, V _{IN} = 0.4V	—	-0.32	-0.45	mA	
	(Output Off)	I _{IN (OFF)}	4	V _{CC} = 5.5V, V _{IN} = -20V	—	—	-2.6		
Input Voltage (Output On)	TD62384	V _{IN (ON)}	5	—	—	—	V _{CC} - 2.8	V	
	TD62385			—	—	—	V _{CC} - 3.7		
Supply Current		I _{CC (ON)}	6	V _{CC} = 5.5V, V _{IN} = 0	—	17	22	mA	
		I _{CC (OFF)}		V _{CC} = 5.5V, V _{IN} = V _{CC}	—	—	100		μA
Turn-On Delay		t _{ON}	7	V _{CC} = 5V, V _{OUT} = 50V R _L = 163Ω, C _L = 15pF (Note 1)	—	0.1	—	μs	
Turn-Off Delay		t _{OFF}			—	3	—		

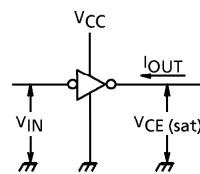
(Note 1) F-Type : V_{OUT} = 35V, R_L = 116Ω

TEST CIRCUIT

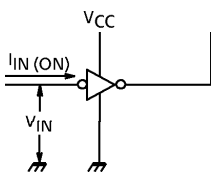
1. I_{CEX}



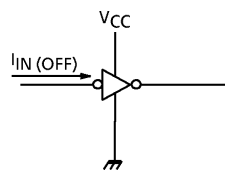
2. $V_{CE(sat)}$



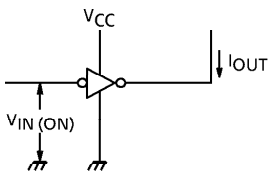
3. $I_{IN(ON)}$



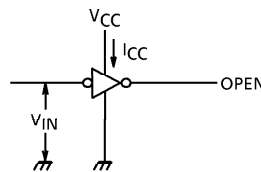
4. $I_{IN(OFF)}$



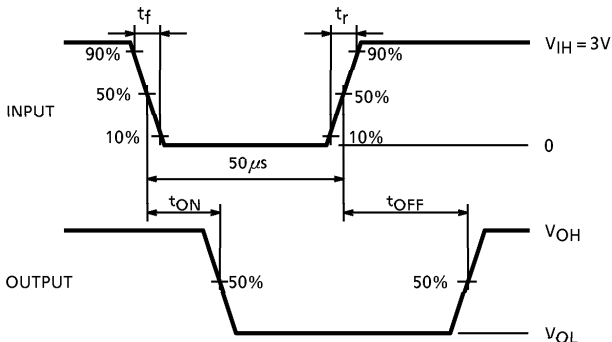
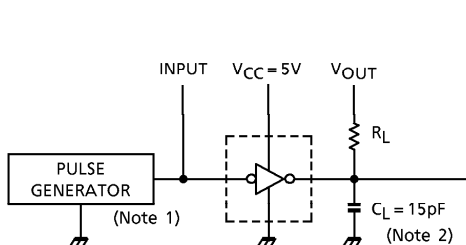
5. $V_{IN(ON)}$



6. I_{CC}



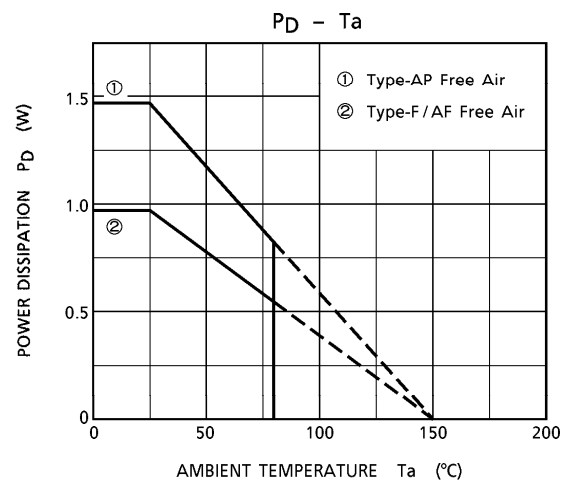
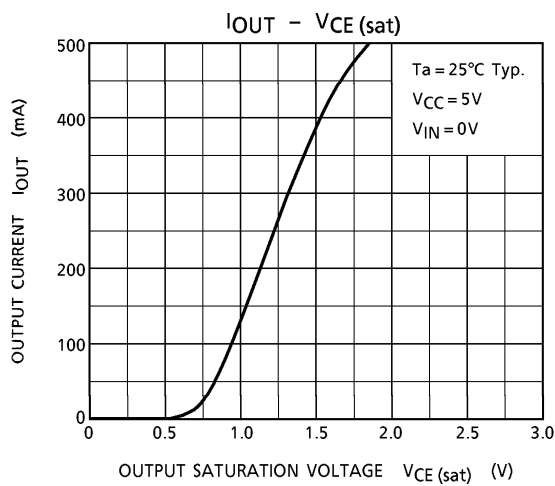
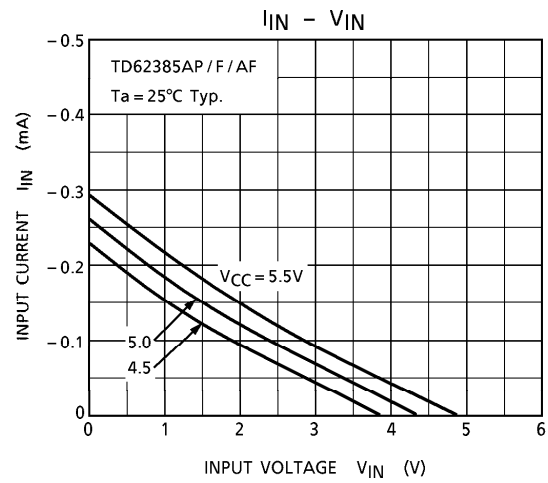
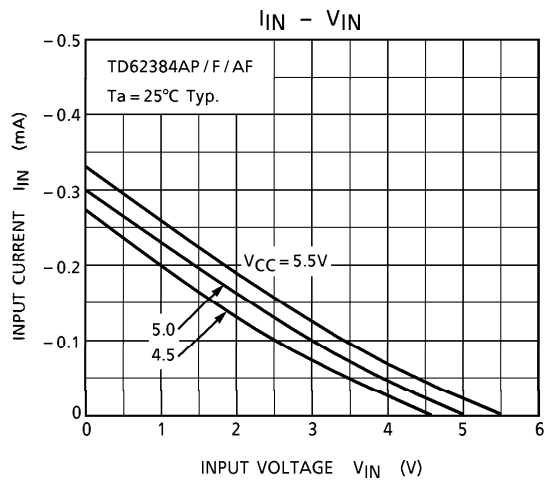
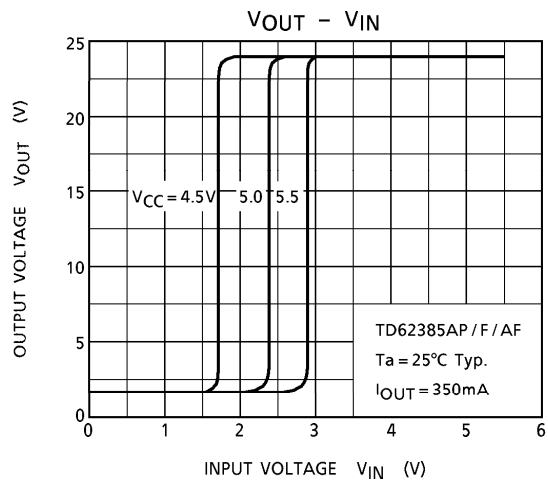
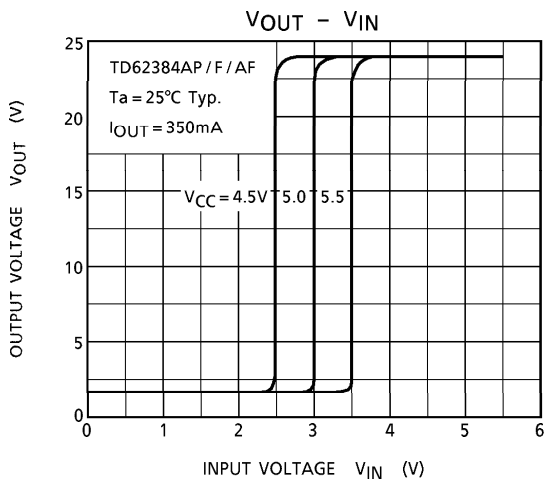
7. t_{ON}, t_{OFF}



- (Note 1) Pulse Width $50\mu s$, Duty Cycle 10%
Output Impedance 50Ω , $t_r \leq 5ns$, $t_f \leq 10ns$
- (Note 2) C_L includes probe and jig capacitance.

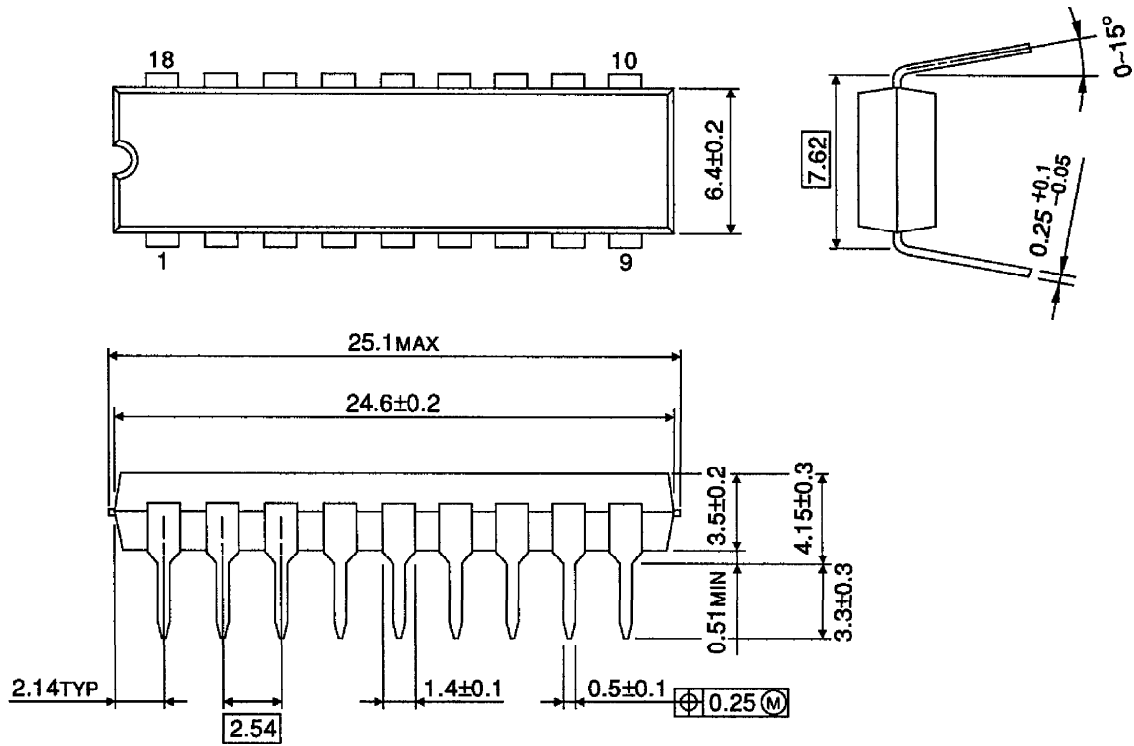
PRECAUTIONS for USING

Utmost care is necessary in the design of the output line, V_{CC} and GND line since IC may be destroyed due to short-circuit between outputs, air contamination fault, or fault by improper grounding.



OUTLINE DRAWING
DIP18-P-300-2.54D

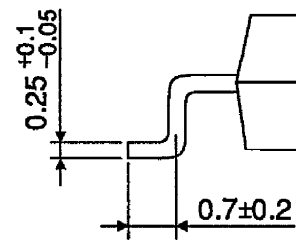
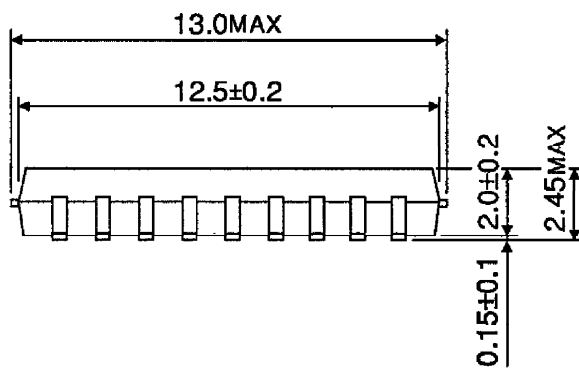
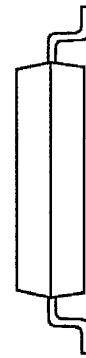
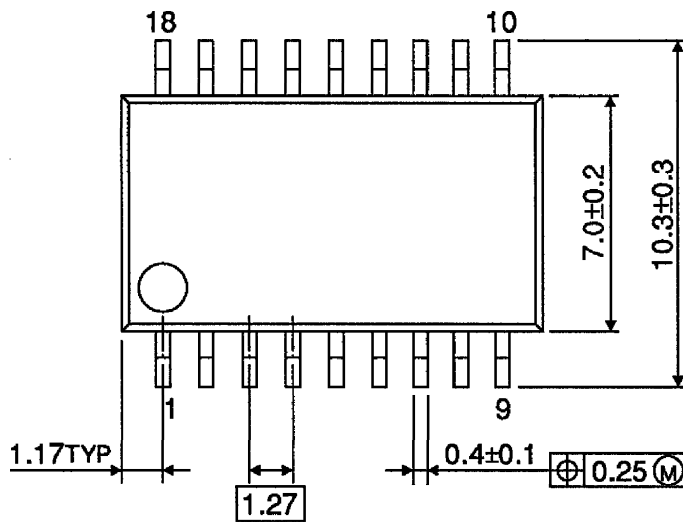
Unit : mm



Weight : 1.47g (Typ.)

OUTLINE DRAWING
SOP18-P-375-1.27

Unit : mm



Weight : 0.41g (Typ.)